Dual High-Speed 1.5A MOSFET Drivers

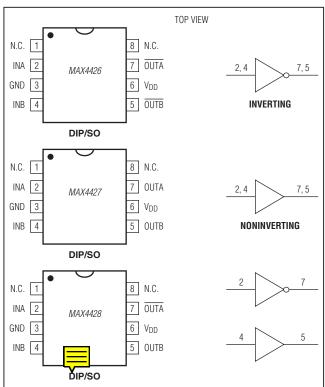
General Description

The MAX4426/MAX4427/MAX4428 are dual monolithic MOSFET drivers designed to translate TTL/CMOS inputs to high voltage/current outputs. The MAX4426 is a dual inverting power MOSFET driver. The MAX4427 is a dual noninverting power MOSFET driver, and the MAX4428 contains one inverting section and one noninverting section. Delay times are nearly independent of VDD (see *Typical Operating Characteristics*). High-current output drivers rapidly charge and discharge the gate capacitance of even the largest power MOSFETs to within millivolts of the supply rails. This produces the power MOSFETs' minimum on resistance. The MAX4426/MAX4427/MAX4428's high speed minimizes power losses in switching power supplies and DC-DC converters.

_Applications

Switching Power Supplies
DC-DC Converters
Motor Controllers
Pin-Diode Drivers
Charge-Pump Voltage Inverters

Pin Configurations



Features

- ♦ Upgrade for TSC4426/TSC4427/TSC4428
- ♦ Lower On Resistance: 4Ω vs. 7Ω
- ♦ Shorter Delay Times: tp1 10ns vs. 30ns

tp2 - 25ns vs. 50ns

- ♦ 1.5A Peak Output Current
- ♦ Fast Rise and Fall Times: Typically 20ns with 1000pF Load
- ♦ Wide Operating Range: 4.5V to 18V
- ♦ Low Power Consumption: 1.8mA with Logic 1 Input 200µA with Logic 0 Input
- **♦ TTL/CMOS Compatible**
- ♦ Latchup Protected-Withstand > 500mA Reverse Current
- **♦ ESD Protected**

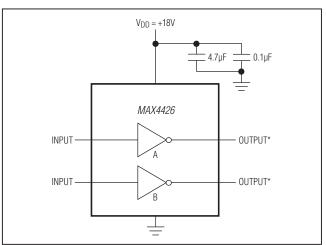
Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	
MAX4426CPA	0°C to +70°C	8 Plastic DIP	
MAX4426CSA	0°C to +70°C	8 SO	
MAX4426C/D	0°C to +70°C	Dice*	
MAX4426EPA	-40°C to +85°C	8 Plastic DIP	
MAX4426ESA	MAX4426ESA -40°C to +85°C		
MAX4426EJA -40°C to +85°		8 CERDIP	
MAX4426MJA	-55°C to +125°C	8 CERDIP**	

Ordering Information continued on end of data sheet.

*Dice are tested at $T_A = +25$ °C.

Typical Operating Circuit



For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maximintegrated.com.

^{**}Contact factory for availability and processing to MIL-STD-883.

Dual High-Speed 1.5A MOSFET Drivers

ABSOLUTE MAXIMUM RATINGS

Supply Voltage VDD to GND+20V
Time V _{IL} < V _{IN} < V _I H
Input VoltageVDD + 0.3V to GND - 0.3V
Continuous Power Dissipation (T _A = +70°C)
Plastic DIP (derate 9.09mW/°C above +70°C)727mW
SO (derate 5.88mW/°C above +70°C)471mW
CERDIP (derate 8.00mW/°C above +70°C)640mW

0°C to +70°C
40°C to +85°C
550°C to +125°C
55°C to +160°C
+150°C
+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

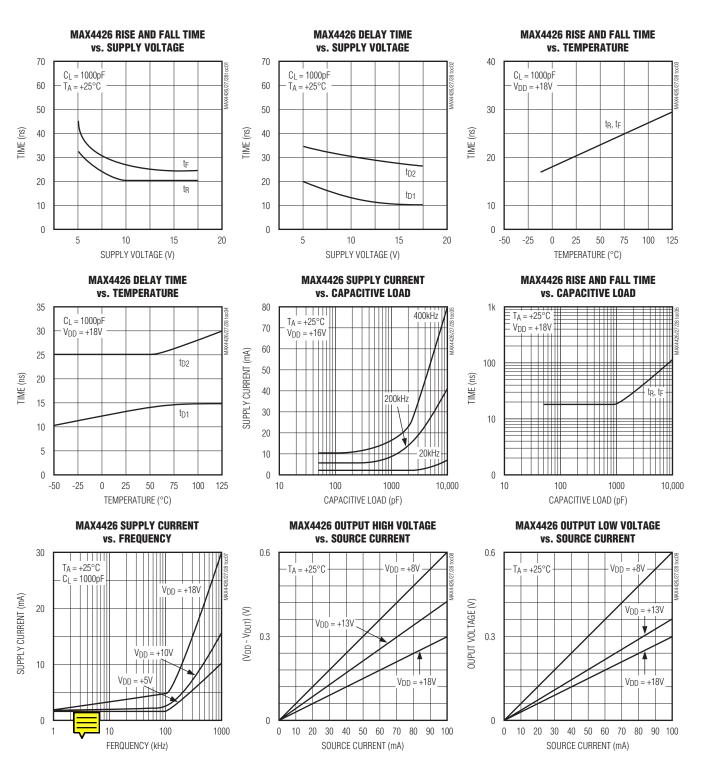
 $(V_{DD} = +4.5V \text{ to } +18V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified.})$

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS		
Logic 1 Input Voltage	VIH					2.4			V
Logic 0 Input Voltage	VIL							0.8	V
Input Current	IIN	VIN = 0V to	V _{IN} = 0V to 18V		-1		1	μΑ	
Output High Voltage	Vон	No load	No load		V _{DD} - 25			mV	
Output Low Voltage	VoL	No load						25	mV
Output Resistance		V _{DD} = 18V, I _{LOAD} = 10mA	V _{IN} = 0.8V for inverting stage V _{IN} = 2.4V for		T _A = +25°C		4	10	
	Rout		noninverti stages		TA = TMIN to TMAX		5	12	Ω
	11001		V _{IN} = 2.4V for inverting stages, V _{IN} = 0.8V for		T _A = +25°C		4	10	2
			noninvertin stages		TA = TMIN to		5	12	
Peak Output Current	IPK	V _{DD} = 18V	V _{DD} = 18V			1.5		Α	
Power-Supply Current		$ \begin{array}{c} \text{VIN} = +3 \text{V for both} \\ \text{inputs} \end{array} \qquad \begin{array}{c} \text{TA} = +25 ^{\circ} \text{C} \\ \text{TA} = \text{TMIN to TMAX} \end{array} $ $ \begin{array}{c} \text{VIN} = 0 \text{V for both} \\ \text{inputs} \end{array} \qquad \begin{array}{c} \text{TA} = +25 ^{\circ} \text{C} \\ \text{TA} = +25 ^{\circ} \text{C} \end{array} $			1.8	4.5			
	ISUPP			MIN to TMAX		2.5	8.0	mA	
	ISUPP			-25°C		0.2	0.4		
					0.3	0.6			
Rise Time (Note 1)	t _R	TA = +25°C			20	30	ns		
Trise fille (Note 1)	, n	TA = TMIN to	TMAX				25	40	110
Fall Time (Note 1)	all Time (Note 1) $TA = +25^{\circ}C$		20	20	30	ns			
Tall Time (Note 1)	· ·	TA = TMIN to TMAX			25	40	110		
Delay Time (Note 1)	t _{D1}	TA = +25°C			10	30	ns		
	101	TA = TMIN to TMAX			15	40			
Doiay Timo (140to 1)	t _{D2}	$T_A = +25^{\circ}C$					25	50	ns
	الماد	TA = TMIN to	TMAX		_		30	60	110

Note 1: Switching times guaranteed by design, not tested. See Figure 1 for timing measurement circuit.

Dual High-Speed 1.5A MOSFET Drivers

Typical Operating Characteristics



Dual High-Speed 1.5A MOSFET Drivers

Applications Information

The MAX4426/MAX4427/MAX4428 have easy-to-drive inputs. However, these inputs must never be allowed to stay between VIH and VIL for more than 50ns. Unused inputs should always be connected to ground to minimize supply current. Drivers can be paralleled on the MAX4426 or MAX4427 by tying both Inputs together and both outputs together.

Supply bypassing and grounding are extremely important with the MAX4426/MAX4427/MAX4428, as the peak supply current can be as high as 3A, which is twice the peak output current. Ground drops are a form of negative feedback with inverters, and hence will degrade the delay and transition time of the MAX4426/MAX4428.

Suggested bypass capacitors are a 4.7µF (low ESR) capacitor in parallel with a 0.1µF ceramic capacitor, mounted as close as possible to the MAX4426/ MAX4427/MAX4428. Use a ground plane if possible or separate ground returns for inputs and outputs. Output voltage ringing can be minimized with a 5Ω to 20Ω resistor in series with the output, but this will degrade output transition time. Ringing may be undesirable due to the large current that flows through capacitive loads when the voltage across these loads transitions quickly.

Operation at the upper end of the supply voltage range (> 15V) requires that a capacitance of at least 50pF be present at the outputs. This prevents the supply voltage provided to the die (which can be different from that seen at the supply pin) from exceeding the 20V absolute maximum rating, due to overshoot. Since at least 50pF of gate capacitance is present in all higher power FETs, this requirement is easily met.

Power Dissipation

The MAX4426/MAX4427/MAX4428 power dissipation consists of input inverter losses, crowbar current through the output devices, and output current (either capacitive or resistive). The sum of these must be kept below the maximum power dissipation limit.

The DC input inverter supply current is 0.2mA when both inputs are low and 2mA when both inputs are high. The crowbar current through an output device making a transition is approximately 100mA for a few nanoseconds. This is a small portion of the total supply current, except for high switching frequencies or a small load capacitance (100pF).

The MAX4426/MAX4427/MAX4428 power dissipation when driving a ground-referenced resistive load is:

$$P = (D) (ron(MAX)) (ILOAD^2)$$

where D is the percentage of time the MAX4426/MAX4427/MAX4428 output pulls high, ron(MAX) is the MAX4426/MAX4427/MAX4428 maximum on resistance, and ILOAD is the MAX4426/MAX4427/MAX4428 load current.

For capacitive loads, the power dissipation is:

$$P = (CLOAD) (VDD^2) (FREQ)$$

where CLOAD is the capacitive load. VDD is the MAX4426/MAX4427/MAX4428 supply voltage, and FREQ is the toggle frequency.



Dual High-Speed 1.5A MOSFET Drivers

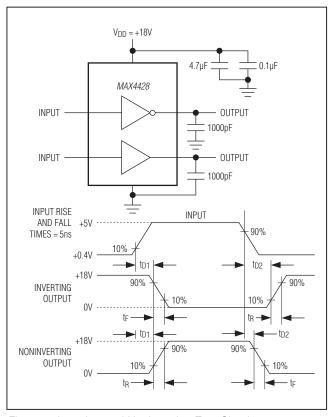


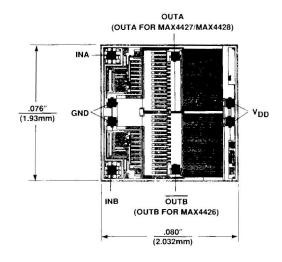
Figure 1. Inverting and Noninverting Test Circuit

_Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
MAX4427CPA	0°C to +70°C	8 Plastic DIP
MAX4427CSA	0°C to +70°C	8 SO
MAX4427C/D	0°C to +70°C Dice*	
MAX4427EPA	-40°C to +85°C	8 Plastic DIP
MAX4427ESA	-40°C to +85°C	8 SO
MAX4427EJA	-40°C to +85°C	8 CERDIP
MAX4427MJA	-55°C to +125°C	8 CERDIP**
MAX4428CPA	0°C to +70°C	8 Plastic DIP
MAX4428CSA	0°C to +70°C	8 SO
MAX4428C/D	0°C to +70°C	Dice*
MAX4428EPA	-40°C to +85°C	8 Plastic DIP
MAX4428ESA	-40°C to +85°C	8 SO
MAX4428EJA	-40°C to +85°C	8 CERDIP
MAX4428MJA	-55°C to +125°C	8 CERDIP**

^{*}Dice are tested at $T_A = +25$ °C.

Chip Topography



SUBSTRATE CONNECTED TO V_{DD}; TRANSISTOR COUNT: 26.

MAX4427/MAX4428

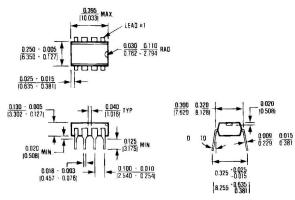


^{**}Contact factory for availability and processing to MIL-STD-883.

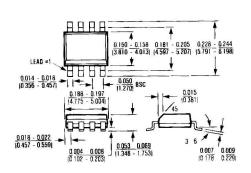
Dual High-Speed 1.5A MOSFET Drivers

Package Information

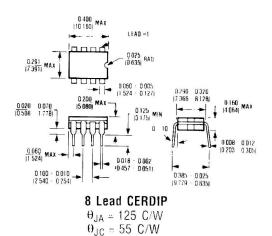
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



8 Lead Plastic DIP $\theta_{JA} = 120^{\circ}\text{C/W}$ $\theta_{JC} = 70^{\circ}\text{C/W}$



8 Lead Small Outline $\theta_{JA} = 170 \text{ C/W}$ $\theta_{JC} = 80 \text{ C/W}$





Dual High-Speed 1.5A MOSFET Drivers

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
2	6/06	To clarify and illuminate an input logic level restriction	_



Maxim canno the responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves are right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.